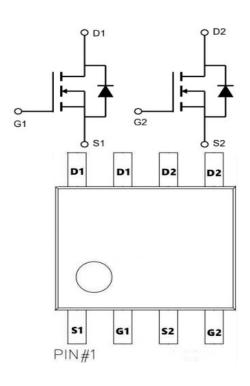


## Description

The SX12V04S uses advanced trench technology to provide excellent RDS(ON), low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.



#### **General Features**

 $V_{DS} = -40V I_{D} = -12A$ 

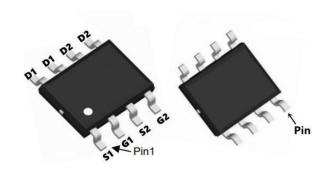
 $R_{DS(ON)}$  < 18m $\Omega$  @ V<sub>GS</sub>=-10V

## **Application**

Battery protection

Load switch

Uninterruptible power supply



Absolute Maximum Ratings (TC=25℃unless otherwise noted)

Symbol	Parameter	Rating	Units	
V <sub>DS</sub>	Drain-Source Voltage	-40	V	
Vgs	Gate-Source Voltage	±20	V	
<b>b@T</b> c=25℃	Continuous Drain Current, V <sub>GS</sub> @ -10V <sup>1</sup>	-12	Α	
<b>l</b> b@Tc=100℃	Continuous Drain Current, V <sub>GS</sub> @ -10V <sup>1</sup>	-6.9	Α	
<b>I</b> DM	Pulsed Drain Current <sup>2</sup>	-36	А	
EAS	Single Pulse Avalanche Energy³	125	mJ	
Pb@Tc=25°C	Total Power Dissipation <sup>4</sup>	1.3	W	
Тѕтс	Storage Temperature Range	-55 to 150	$^{\circ}$	
TJ	Operating Junction Temperature Range	-55 to 150	$^{\circ}$	
Reja	Thermal Resistance Junction-Ambient <sup>1</sup>	85	°C/W	
Rejc	Thermal Resistance Junction-Case <sup>1</sup>	5	°C/W	



## Electrical Characteristics (T」=25℃, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage	Vgs=0V , In=-250uA	-40	-44		V
△BVɒss/△T	BV <sub>DSS</sub> Temperature Coefficient	Reference to 25°C , I <sub>D</sub> =-1mA		-0.023		V/°C
1	Static Drain-Source On-Resistance <sup>2</sup>	Vgs=-10V , In=-30A		15	18	mΩ
RDS(ON)		V <sub>G</sub> s=-4.5V , I <sub>D</sub> =-20A		18	25	
V <sub>GS(th)</sub>	Gate Threshold Voltage	\/ \/ I 050\	-1.0	-1.6	-2.5	V
△VGS(th)	V <sub>GS(th)</sub> Temperature Coefficient	Vgs=Vds , Id=-250uA		4.74		mV/℃
loss	Drain Source Leakage Current	V <sub>DS</sub> =-40V , V <sub>GS</sub> =0V , T <sub>J</sub> =25℃			1	uA
	Drain-Source Leakage Current	V <sub>DS</sub> =-40V , V <sub>GS</sub> =0V , T <sub>J</sub> =55℃			5	uA
lgss	Gate-Source Leakage Current	Vgs=±20V , Vps=0V			±100	nA
Qg	Total Gate Charge (-4.5V)			25		nC
Qgs	Gate-Source Charge	V <sub>DS</sub> =-20V , V <sub>GS</sub> =-4.5V , l <sub>D</sub> =-12A		11		
$\mathbf{Q}_{gd}$	Gate-Drain Charge	D12A		9.5		
Td(on)	Turn-On Delay Time			48		ns
Tr	Rise Time	VDD =-15V, RL=15Ω		24		
Td(off)	Turn-Off Delay Time	ID =-1A, VGEN =-10V, RG =6Ω		88		
Tf	Fall Time	1.5		9.6		
Ciss	Input Capacitance			2760		
Coss	Output Capacitance	V <sub>DS</sub> =-20V , V <sub>GS</sub> =0V , f=1MHz		260		pF
Crss	Reverse Transfer Capacitance			85		
ls	Continuous Source Current <sup>1,5</sup>	Vo=Vo=0V Force Current			-40	Α
lsм	Pulsed Source Current <sup>2,5</sup>	V <sub>G</sub> =V <sub>D</sub> =0V , Force Current			-90	Α
VsD	Diode Forward Voltage <sup>2</sup>	Vgs=0V , Is=-1A , Tյ=25℃			-1.3	V

#### Note:

- 1. The data tested by surface mounted on a 1 inch2 FR-4 board with 2OZ copper.
- 2 . The data tested by pulsed , pulse width  $\leq 300 \text{us}$  , duty cycle  $\leq 2\%$
- $3 \times \text{The EAS}$  data shows Max. rating . The test condition is VDD=-32V,VGS=-10V,L=0.1mH,IAS=-30A
- $4\,{\scriptstyle \searrow}$  The power dissipation is limited by  $150\,{\rm ^{\circ}}$  junction temperature
- 5. The data is theoretically the same as ID and IDM, in real applications, should be limited by total power dissipation.

2

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# **Typical Characteristics**

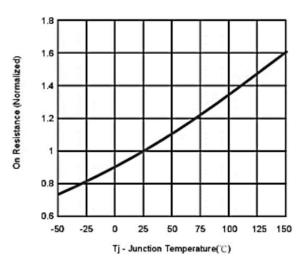
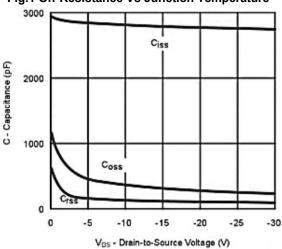


Fig.1 On Resistance Vs Junction Temperature



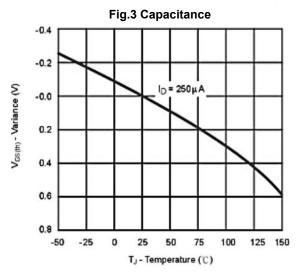


Fig.5 Threshold Voltage

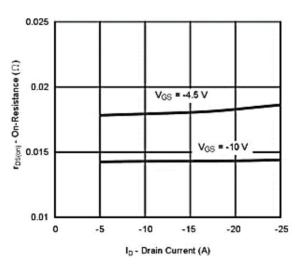


Fig.2 On-Resistance Vs.Drain Current

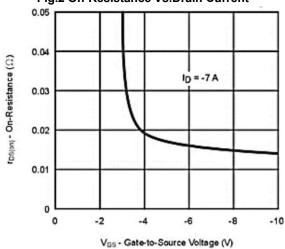


Fig.4 On-Resistance Vs. Gate-to-Sourece Voltage

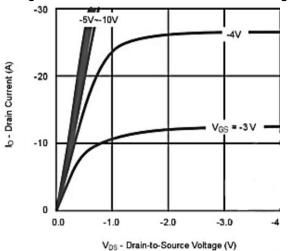


Fig.6 On-Region Characteristics



## **Typical Characteristics**

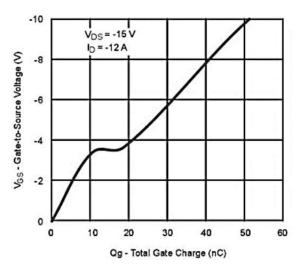


Fig.7 Gate Charge

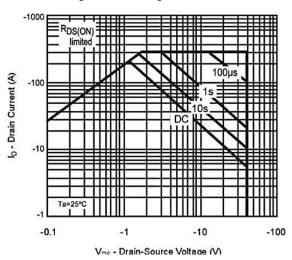


Fig.9 Safe Operating Area

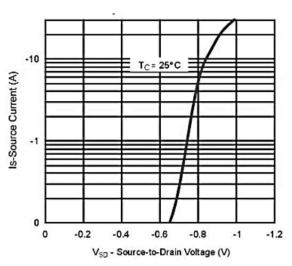


Fig.8 Body-diode Characteristice

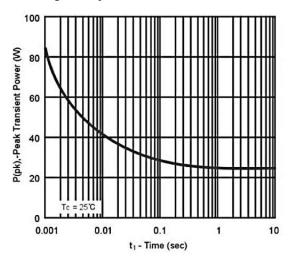


Fig.10 Single Pluse Maximum Power Dissipation

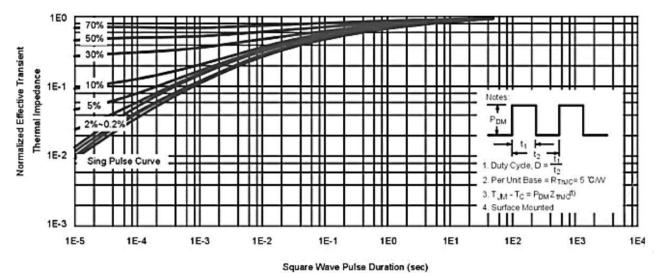
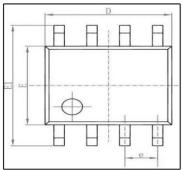
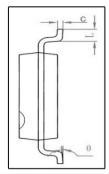


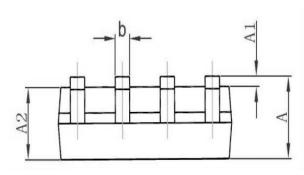
Fig.11 Normalized Maximum Transient Thermal Impedance



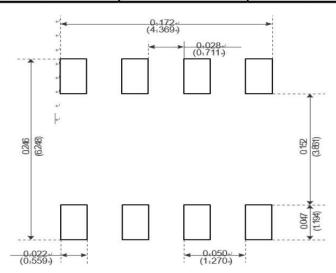
# Package Mechanical Data-SOP-8L







Symbol	Dimensions In	n Millimeters	Dimensions	In Inches
	Min	Max	Min	Max
Α	1. 350	1. 750	0. 053	0.069
A1	0. 100	0. 250	0. 004	0. 010
A2	1. 350	1. 550	0. 053	0. 061
b	0. 330	0. 510	0. 013	0. 020
С	0. 170	0. 250	0.006	0. 010
D	4. 700	5. 100	0. 185	0. 200
E	3. 800	4. 000	0. 150	0. 157
E1	5. 800	6. 200	0. 228	0. 244
е	1. 270	(BSC)	0.050	(BSC)
L	0. 400	1. 270	0. 016	0. 050
θ	0°	8°	0°	8°



Recommended Minimum Pads

**Package Marking and Ordering Information** 

Product ID	Pack	Marking	Qty(PCS)
TAPING	SOP-8L		3000

5